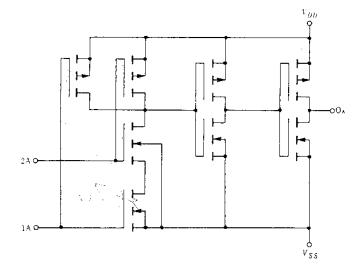
# HD14011B

Quadruple 2-input NAND Gate

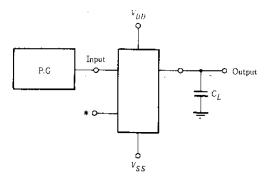
#### **FEATURES**

- Quiescent Current = 0.5nA typ/pkg@5V
  Noise Immunity = 45% of VDD typ
  Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pin-for Pin Replacements for CD4011B and MC14011B Series

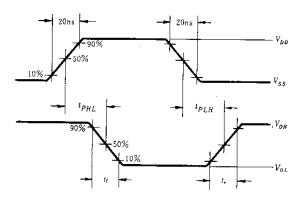
#### **CIRCUIT SCHEMATIC** (1/4)



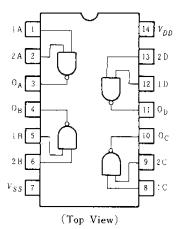
### SWITCHING TIME TEST CIRCUIT



\* All unused inputs of AND, NAND gates must be connected to  $V_{DD}$ .



#### PIN ARRANGEMENT



Downloaded from Elcodis.com electronic components distributor

Characteristic	Symbol	<u> </u>	Test Conditions	-40°C			25°C			85°C	
Ondracteristic		$V_{DD}(\mathbf{V})$		min	max	min	typ	max	min	max	Unit
Output Voltage	Vol	5.0		_	0.05	—	0	0.05	—	0.05	v
		10	$V_{in} = V_{DD}$		0.05	_	0	0.05	_	0.05	
		15		_	0.05	-	0	0.05		0.05	
	Voн	5.0	$V_{in} = 0$	4.95	_	4.95	5.0	_	4.95	-	V
		10		9.95	—	9.95	10	<b>-</b> '	9.95		
		15		14.95	-	14.95	15	—	14.95	_	
Input Voltage -		5.0	$V_{out} = 4.5 V$	-	1.5	_	2.25	1.5		1.5	v
	VIL	10	$V_{out} = 9.0 \mathrm{V}$		3.0	-	4.50	3.0	_	3.0	
		15	$V_{out} = 13.5 \mathrm{V}$	-	4.0	-	6.75	4.0	_	4.0	
		5.0	$V_{out}=0.5\mathrm{V}$	3.5		3.5	2.75	-	3.5	_ !	v
	ViH	10	$V_{out} = 1.0 \mathrm{V}$	7.0	-	7.0	5.50	-	7.0	-	
		15	$V_{out} = 1.5 V$	11.0	-	11, 0	8.25	-	11.0.	-	
Output Drive Current	Іон	5.0	$V_{OH} = 2.5 \mathrm{V}$	-2.5	-	-2.1	-4.2	_	-1.7	_ !	mA
		5.0	$V_{OH} = 4.6V$	-0.52	-	-0.44	-0.88	—	-0.36	<u> </u>	
		10	$V_{OH} = 9.5 \mathrm{V}$	-1.3	-	-1.1	-2.25		-0.9		
		15	$V_{OH} = 13.5 \mathrm{V}$	-3.6	-	-3.0	- 8.8	-	-2.4	_	
	Iol	5.0	$V_{OL} = 0.4 V$	0.52	-	0.44	0.88		0.36	·	mA
		10	$V_{OL} = 0.5V$	1.3	-	1.1	2.25	-	0.9	-	
		15	$V_{OL} = 1.5 V$	3.6	-	3.0	8.8	—	2.4	-	
Input Current	Lin	15		-	±0.3	—	±0.00001	±0.3	-	±1.0	μA
Input Capacitance	Cin		$V_{in}=0$	-	-	-	5.0	7.5	-	_	pF
Quiescent Current	IDD	5.0	Zero Signal, per Package	—	1.0	—	0.0005	1.0	—	7.5	μA
		10			2.0	—	0.0010	2.0	-	15.0	
		15			4.0	-	0.0015	4.0	_	30.0	
Total Supply Current*	IT	5.0	Dynamic $+I_{OD}$ , $C_L = 50 \text{pF}$		_	_	0.3	_	-	-	μA
		10	per Gate,			—	0.6				
	1	15	$f=1 \mathrm{kHz}$		_	_	0.9	_	_	_	

## **ELECTRICAL CHARACTERISTICS**

\* To calculate total supply current at frequency other than lkHz.  $\approx V_{DD} \approx 5.0V \quad l_T = :0.3 \mu A / kHz \cdot f + \frac{l_{DD}}{4} \qquad \ll V_{DD} = 10V \quad l_T = :0.6 \mu A / kHz \cdot f + \frac{l_{DD}}{4} \qquad \ll V_{DD} = 15V \quad h = :0.9 \mu A / kHz \cdot f + \frac{l_{DD}}{4}$ 

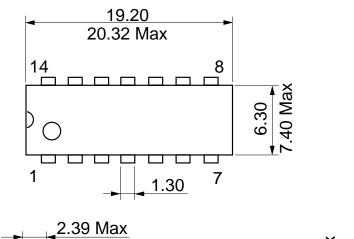
## **SWITCHING CHARACTERISTICS** $(C_L = 50 \text{pF}, Ta = 25^{\circ}\text{C})$

Characterístic	Symbol	$V_{DD}(\mathbf{V})$	min	typ	max	Unit
Output Rise Time	t r	5.0	_	100	200	ns
		10	-	50	100	
		15		40	80	
Output Fall Time	tj	5.0	_	100	200	ns
		10	_	50	100	
		15		40	80	
Propagation Delay Time	t <sub>PLH</sub>	5.0	_	125	250	ns
		10	_	50	100	
		15	_	40	80	
	t <sub>PHL</sub>	5.0		125	250	ns
		10		50	100	
		15		40	80	]

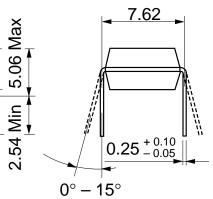


42

Unit: mm



 $0.48 \pm 0.10$ 



0.51 Min

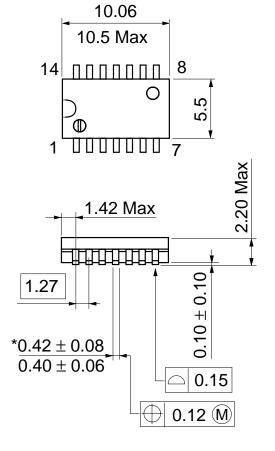
RANK

Hitachi Code	DP-14
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.97 g

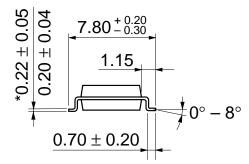
 $2.54\pm0.25$ 

Unit: mm





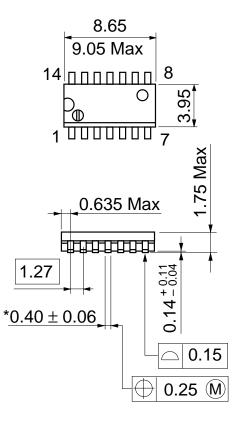
\*Dimension including the plating thickness Base material dimension



Hitachi Code	FP-14DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.23 g

Unit: mm



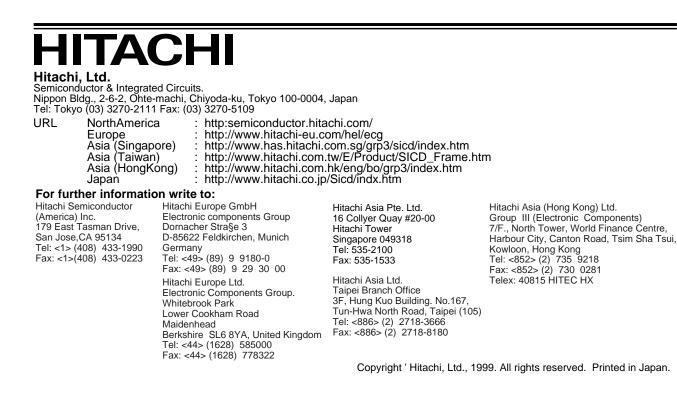


Hitachi Code	FP-14DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.13 g

\*Pd plating

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